TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC5096

VHF~UHF Band Low Noise Amplifier Applications

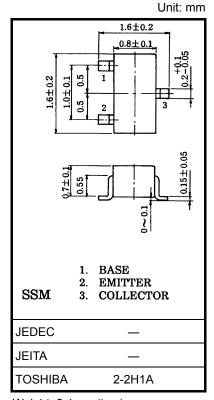
- Low noise figure, high gain.
- NF = 1.8dB, $|S_{21e}|^2 = 7.5dB$ (f = 2 GHz)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	20	V	
Collector-emitter voltage	V _{CEO}	10	V	
Emitter-base voltage	V _{EBO}	1.5	V	
Base current	ΙΒ	7	mA	
Collector current	IC	15	mA	
Collector power dissipation	PC	100	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	−55~125	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 2.4 mg (typ.)

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	ol Test Condition		Тур.	Max	Unit	
Transition frequency	f _T	$V_{CE} = 6 \text{ V}, I_{C} = 7 \text{ mA}$	7	10	_	GHz	
Insertion gain	S _{21e} ² (1)	$V_{CE} = 6 \text{ V}, I_{C} = 7 \text{ mA}, f = 1 \text{ GHz}$	_	13	_	dB	
	S _{21e} ² (2)	$V_{CE} = 6 \text{ V}, I_{C} = 7 \text{ mA}, f = 2 \text{ GHz}$	4.5	7.5	_	uБ	
Noise figure	NF (1)	$V_{CE} = 6 \text{ V}, I_{C} = 3 \text{ mA}, f = 1 \text{ GHz}$	_	1.4	_	- dB	
	NF (2)	$V_{CE} = 6 \text{ V}, I_{C} = 3 \text{ mA}, f = 2 \text{ GHz}$	_	1.8	3.0		

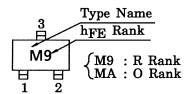
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$	_	_	1	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = 1 \text{ V, } I_C = 0$	_	_	1	μА
DC current gain	h _{FE} (Note 1)	V _{CE} = 6 V, I _C = 7 mA	50	_	160	
Output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz (Note 2)	_	0.5		pF
Reverse transfer capacitance	C _{re}	VCB = 10 V, 1E = 0, 1 = 1 IMIDZ (Note 2)	_	0.4	0.85	pF

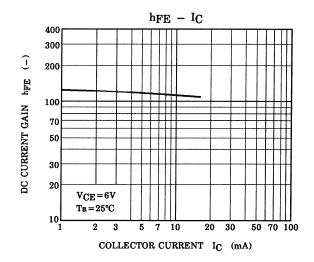
Note 1: hFE classification R: 50~100, O: 80~160

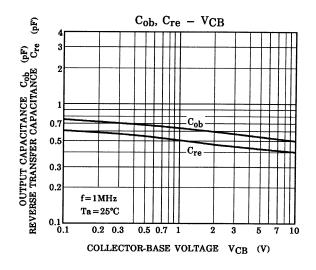
Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

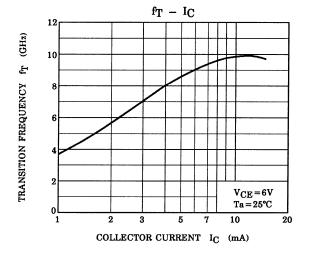
Marking

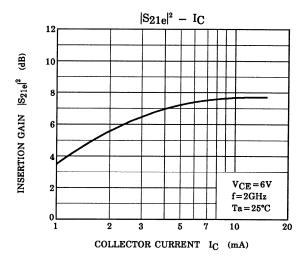


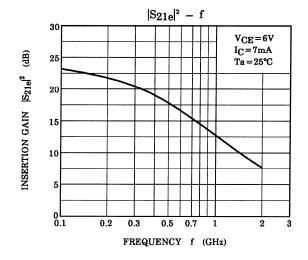
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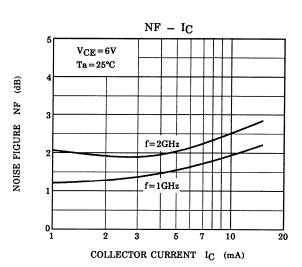


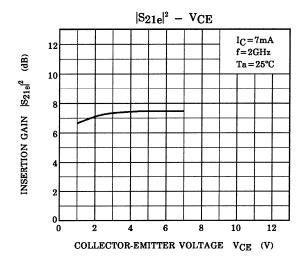


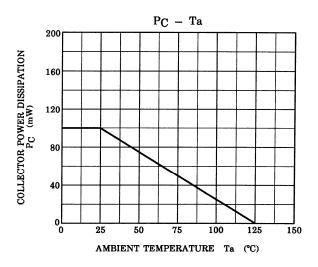












S-Parameter $Z_O = 50 \Omega$, $Ta = 25^{\circ}C$

$V_{CE} = 6 V$, $I_C = 3 mA$

Frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.835	-26.1	7.069	150.4	0.046	71.0	0.899	-19.3
400	0.665	-46.5	5.948	130.4	0.076	60.5	0.745	-30.3
600	0.501	-62.7	5.021	115.2	0.095	55.7	0.630	-35.9
800	0.386	-74.3	4.173	104.3	0.111	53.7	0.552	-38.5
1000	0.297	-83.7	3.592	95.6	0.124	53.2	0.500	-39.9
1200	0.226	-92.7	3.140	88.5	0.137	53.6	0.465	-41.1
1400	0.175	-101.9	2.808	82.3	0.152	54.1	0.442	-42.2
1600	0.130	-113.4	2.514	76.6	0.165	54.2	0.421	-43.8
1800	0.103	-128.0	2.293	71.7	0.179	53.9	0.405	-45.7
2000	0.081	-147.4	2.114	67.3	0.193	54.8	0.388	-47.4

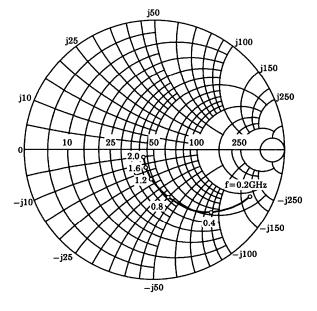
$V_{CE} = 6 V$, $I_C = 7 mA$

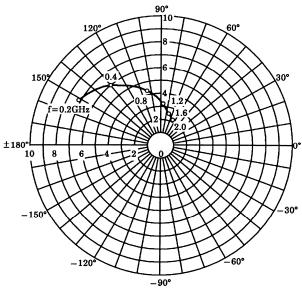
Frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.668	-40.0	12.306	138.9	0.040	67.3	0.786	-27.0
400	0.427	-64.4	8.852	116.1	0.061	61.6	0.579	-35.0
600	0.280	-79.5	6.591	102.9	0.078	61.8	0.476	-35.9
800	0.193	-89.7	5.191	94.3	0.096	62.5	0.420	-35.0
1000	0.134	-99.3	4.288	87.8	0.112	63.2	0.390	-34.2
1200	0.088	-112.3	3.661	81.9	0.130	63.8	0.374	-34.0
1400	0.056	-129.8	3.232	76.9	0.150	63.4	0.366	-34.8
1600	0.035	-169.0	2.857	72.1	0.168	62.5	0.356	-36.6
1800	0.040	157.0	2.574	68.1	0.185	61.4	0.347	-39.0
2000	0.054	131.5	2.363	64.3	0.203	61.3	0.338	-40.2

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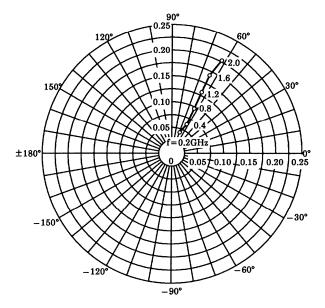
 $\begin{array}{l} S_{11e} \\ V_{CE} = 6V \\ I_{C} = 3mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$







 $\begin{array}{c} S_{12e} \\ V_{CE} = 6V \\ I_{C} = 7mA \\ T_{a} = 25^{\circ}C \end{array}$

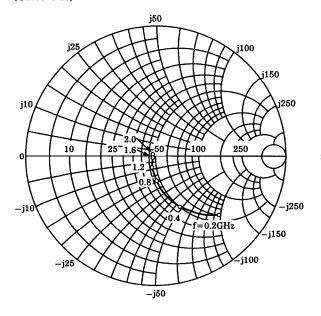


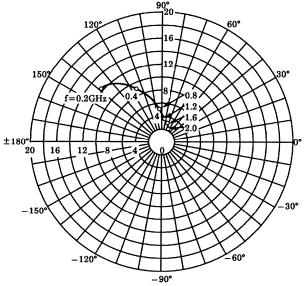
 $\begin{array}{c} S22e \\ VCE = 6V \\ IC = 7mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \\ j25 \\ 0 \\ 10 \\ 25 \\ 50 \\ 100 \\ 250 \\ 250 \\ 100 \\ 250 \\ 100 \\ 250 \\ 100 \\ 250 \\ 100 \\ 250 \\ 100 \\ 250 \\ 100 \\ 1250 \\ 100 \\ 1250 \\ 100 \\ 1$

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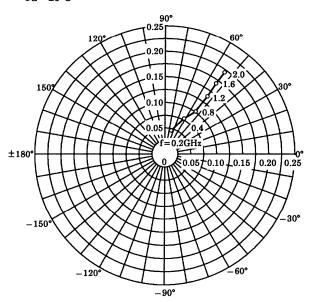
 $\begin{array}{l} S_{11e} \\ V_{CE} = 6V \\ I_{C} = 7mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$





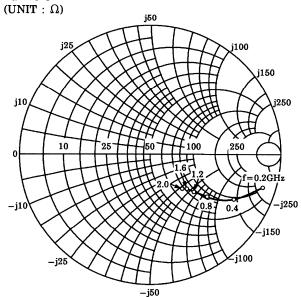


 S_{12e} $V_{CE}=6V$ $I_{C}=3mA$ $Ta=25^{\circ}C$



 S_{22e} $V_{CE} = 6V$ $I_{C} = 3mA$ $T_{a} = 25^{\circ}C$ $(UNIT : \Omega)$

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